Flow-induced voltage and current generation in carbon nanotubes

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Abstract

New experimental results, and a plausible theoretical understanding thereof, are presented for the ow-induced currents and voltages observed in single-walled carbon nanotube samples. In our experiments, the electrical response was found to be sublinear { nearly logarithmic { in the ow speed over a wide range, and its direction could be controlled by an electrochemical biasing of the nanotubes. These experimental indings are inconsistent with the conventional idea of a stream ing potential as the electric cause. Here we present Langevin-equation based treatment of the nanotube charge carriers, assumed to be moving in the uctuating eld of ions in the owing liquid. The resulting \D oppler-shifted" force-force correlation, as seen by the charge carriers drifting in the nanotube, is shown to give a sublinear response, broadly in agreement with experiments.

Single-walled carbon nanotubes (SWNT) in contact with a owing liquid provide a unique m icro uidic system that o ers a large interfacial area of intim ate atom ic contact between the liquid and the solid substrate. This can lead to a strong coupling of the charge carriers in the nanotube to the particles in the owing liquid, more so if the liquid is polar or ionic in character. The e ect of this coupling is expected to be further enhanced due to charge carrier entrainm ent because of the quasi-one dimensionality of the conducting nanotubes. Recently, the ow of a variety of liquids over SW NT bundles was studied experimentally, and was found to generate voltage in the sample along the direction of the ow [1]. Quite unexpectedly, however, the dependence of the voltage on the ow speed was found to be sublinear, and could be tted to a logarithm ic form over ve decades of variation of the speed. There has been an attempt at explaining away this ow-induced voltage in electrokinetic term s as the stream ing potential that develops along the ow of an electrolyte through a m icroporous insulator [2]. Earlier K ral and Shapiro [3] proposed that the shear stress of liquid ow transfers momentum to the acoustic phonons of the nanotube and the resulting \phonon wind" produces a current of carriers in the nanotube. They also suggested, qualitatively, that the uctuating Coulomb elds of the ions in the liquid could drag directly the carriers in the nanotubes. To produce a ow-rate of 1 cm /s in an inter-nanotube channel of 20nm width, as dem anded by the rst mechanism [3] requires an enorm ous pressure head, about 10^{13} dynes/cm². The second mechanism [3] gives currents of order fem to Am peres. In both mechanisms [3], the e ect is linear in the ow rate, in contrast to the experimental ndings [1]. The mechanism we over is related to the second idea of [3] but requires neither localization of carriers nor drag at the same speed as the ions. The main aim of this paper is to report (i) our new experim ental results of the measurem ents of the the short-circuit electrical current as a function of the ow-speed, (ii) ways to control the magnitude and directionality of the ow induced current; and (iii) a general theory for the electrical response consistent with these new observations. Ourm easurem ents clearly rule out the electrokinetic mechanism based on the idea of a stream inq potential. Our theory is based on a stochastic treatment of the nanotube charge-carriers assumed to be moving under the in uence of the correlated ionic uctuations which are advected by the liquid ow. It is broadly consistent with our experiments.

Figure 1 shows a schematic sketch of the construction of the ow sensor. SW NT bundles prepared by arc discharge method [4] are packed between two metal electrodes. The nan-

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otubes are kept in their place by a supporting insulating substrate. The electrical signal is m easured along the ow direction (u_L) as shown Fig. 1. The other experimental details are as in [1]. A sensor with a minimal contact resistance of 25 (found from four-probe measurem ents) was used in the experim ents so that the short-circuit current could be measured. The short-circuit current (open-circuit voltage) was measured by connecting the microam meter (millivoltmeter) across the SW NT sample. The resistance (two-probe) of the device, measured with the sensor dipped in the liquid was found to be 70. Figure 2 shows the dependence of the induced voltage and current on the ow velocity $u_{\rm L}$. The solid line is a t to the empirical relation $I = I \log(I u_L + 1)$; with I = 0.02 A and I = 4.8 10^4 s=cm: The voltage also ts the empirical relation $V = v \log(v u_L + 1)$; where v = 1:4 V and $_{\rm V}$ = 4.8 10⁴ s=cm : It can readily be seen that $_{\rm V}$ = $_{\rm I}$ R, i.e., the resistance encountered is precisely the resistance (2 probe) of the device. This is an in portant point to note: if an electrokinetic mechanism were operating, the resistance obtained would have been orders of m agnitude higher, i.e., equal to that of the electrolyte (0:1M)[5]. This in itself rules out quite decisively the electrokinetic mechanism of voltage generation. Next, we consider the m easured direction of the ow induced current with respect to the ow direction as a function of the bias voltage $V_{\rm B}$ (see inset of Fig.3). This potential biases the SW NT with respect to the Au-reference electrode in mersed in the ow chamber close to sample as shown in the inset of Fig. (3). The dependence of the sign and the magnitude of the ow-induced voltage on $V_{\rm B}$ for an aqueous solution of 0.01 M KCl (conductivity 1:4 m S/m) and for a xed ow speed of 0.04 cm /s is shown in Fig.(3). It is seen that the ow-induced signal is positive, i.e., I is anti-parallel to u_L when V_B is positive, and the sign of the signal is reversed, i.e., I is parallel to u_L , for V_B negative, consistent with our theory. Further, in our theoretical mechanism, based on uctuations, the carriers in the nanotube drift necessarily in the same direction as the ow velocity u_L, quite independently of the sign of the ionic charge. Thus, for the current I to be parallel (antiparallel) to u L the charge carriers in the nanotubes need to be holes (electrons). When the nanotubes are biased positively, the anions (Cl, OH) m ove closer to the SW NT, localizing holes on the carbon and m aking electrons available for ow-induced current. Similarly, holes are liberated when the bias is negative [6]. As the bias voltage is increased the number of carriers participating in the ow-induced current will increase as shown in Fig.(3). Thus, the results obtained by electrochem ically biasing the nanotubes are naturally consistent with our mechanism of (coulombic) forcing of the

nanotube charge carriers by the liquid ow. The dependence of the ow-induced signal on the concentration of di erent types of ions in the liquid is, how ever, found to be complicated and non-monotonic. These details will not be addressed here.

We now turn to our theoretical mechanism for the ow-induced current/voltage. This can be understood qualitatively in terms of three physically distinct but related ideas: (a) Induced friction: The uctuating charge density of the ions close to the nanotube couples could bically to the charge carriers in the nanotube and, therefore, o ers a friction to the motion of these charge carriers (in addition to the 0 hm ic friction intrinsic to the carbon nanotubes). This, of course, follows directly from the uctuation-dissipation theorem; (b) F low-induced drag: In virtue of the above frictional coupling, an imposed liquid ow drags the charge carriers along through the nanotube; (c) Reduction of induced friction at high ow speeds: The space-time correlated couloum bic uctuations, inherent to the liquid electrolyte, are advected by the liquid ow, and thus get Galilean boosted (Doppler shifted) as seen in the mean rest fram e of the drifting carriers in the nanotube. Correspondingly, as we will see, the friction they o er to the motion of the charge carriers in the nanotube dim inishes with increasing ow speed. This is crucial to the observed sublinear dependence of the charge drift-velocity (electrical response) on the liquid ow speed W ith the above in m ind, we will now derive these frictional e ects, rst from a heuristic argument, and then analytically from a Langevin-equation treatment.

Consider a nanotube placed along the the z-axis with the liquid owing parallel to it. We model the nanotube as a classical one-dimensional (ID) conductor with discrete darge transport. In the steady state, let u_L and u_D be, respectively, the velocity of liquid (L) ow and the induced drift velocity of charge carriers in the nanotubes, all measured relative to the nanotube lattice. Now, in the absence of any frictional coupling to the liquid ow, the drift velocity u_D will tend to relax to zero, i.e., to rest with respect to the lattice, with a relaxation time $_D$ characteristic of the nanotube resistivity. Similarly, if we were to \switch o " the resistive coupling to the lattice, the drift velocity u_D would relax to the liquid velocity u_L , i.e., to the rest fram e co-m oving with the liquid, because of the frictional coupling (drag), with a relaxation tim e_L . Now, therefore, in the presence of both these frictional in uences, the drift velocity u_D will assume a steady-state value $u_D < u_L$ that

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satis es $u_D = D_D = (u_L - u_D) = L_D$ giving

$$u_{\rm D} = u_{\rm L} = (1 + L_{\rm L} = D);$$
 (1)

Equation (1) is merely a restatement of the condition of frictional force-balance in the steady state. It would appear to give an induced short-circuit current (equivalently, an open circuit voltage via the nanotube resistance) along the nanotube which is linear in the ow velocity. The nonlinearity is, however, really hidden in the u_L dependence of the relaxation time _L that we will now try to make explicit. It may be noted here that we are assuming, for simplicity, a uniform liquid ow without the hydrodynamic complications of a no-slip boundary condition.

In a simple caricature of the real situation then, consider the ionic density in the liquid, uctuating them ally and owing past the nanotube at a mean velocity $u_L 2$, producing thereby a uctuating couloum bic potential (r;t), at a point r at time t. We are, of course, interested in the case of r lying on the z axis i.e., r = (0;0;z) (in the 1D nanotube). For the space-time correlation function h (0;0) (r;t)i $G_0(r;t)$ in the mean rest frame of the ions, the charge carriers in the nanotube see this correlation G alilean boosted to G(r;t) $G_0(r 2vt;t)$ with $v = u_L$ u_D . This G alilean boost (D oppler shift) is the key physical point of our treatment. At $u_L = 0$, the uctuation-dissipation theorem (FDT) tells us that the coe cient of the zero-frequency friction to the motion of the charge carriers in the nanotubes, arising from the ionic therm al uctuations, is proportional to the time integral of this on-site force-force correlation function. If we assume this relation even for $u_L \notin 0$ we have

$$l = L = 1 = (m_e k_B T) \int_{1}^{2} he E_z (r 2vt; t) e E_z (r; 0) idt;$$
(2)

Here E_z is the z-component of the coulombic (electric) eld due to the ions; m_e is the mass of the charge carrier with e the electronic charge; k_B is the Boltzm an constant, and T the absolute temperature. We re-write the right hand side of Eqn.(2) in Fourier (q)-space, expressing the above force-force correlator in terms of the ionic charge-densities (r;t) using $E_z(q;t) = iq_z(q;t)$ and $q^2(q) = e(q;t) = ,$ where is the solvent dielectric constant, and obtain straightforwardly

$$\frac{1}{L} = \frac{1}{m_{e}k_{B}T} - \frac{4}{2} \frac{e^{2}}{2} \frac{2}{2} \frac{Z}{2} - \frac{dq}{(2)^{3}} - \frac{q^{2}}{q^{4}} - \frac{q^{2}}{q^{2}+2} \frac{1}{2} - \frac{2}{(vq_{z})^{2} + (1-q)^{2}}$$
(3)

$$= \frac{0}{4 \text{ m}_{e}\text{D} \text{ k}_{B}\text{T}} \frac{4 \text{ e}^{2}}{1 \text{ e}^{2}} \frac{1}{x} 1 \frac{2}{x} + \frac{1}{x^{2}} \log 1 \frac{2}{x} \frac{1}{x^{2}} \log \frac{1}{1 + x}$$
(4)

where x = v=D, and $_0$ is the mean ionic number density. In Eqns. (3) and (4) we have used the D ebye -screened form for the static charge structure factor $S_q^0 = h_q_q i = q^2 = (q^2 + 2)$ with screening length 1 as the inverse of the D ebye screening length and a di usive form $1 = _q = D q^2$ [7] with D the ionic di usion constant. It can be seen at once that Eqn.(4), taken in conjunction with Eqn.(2), gives a drift velocity u_D (and therefore the short-circuit current) as a sublinear function of the ow velocity u_L . This sublinearity is a generic feature of this mechanism, and is clearly seen in inset of Fig.(2) in which we have plotted the induced current versus the liquid ow speed derived directly from Eqn.(4) for certain choice of parameters. Rather than attempting to justify this use of the regression form ula in a nonequilibrium context, we turn instead to a direct evaluation of the drift speed starting from a Langevin equation. We recover the same sublinear functional form for the response as in Eqn.(3).

The one-dimensional (1D) position z(t) of a tagged charge carrier in the nanotube obeys the overdam ped Langevin equation

$$\frac{\mathrm{d}z}{\mathrm{d}t} = F(z(t);t) + f(t)$$
(5)

where F (z(t);t) is the uctuating force the ions exert on the carrier at z(t) in the nanotube, and f and are the therm all G aussian white noise and friction intrinsic to the nanotube, with hf (0) f (t) i = $2k_B T$ (t). Strictly speaking, F (z(t);t) should be a function of the instantaneous separations between the positions z(t) of the tagged carriers in the nanotube and those of all the ions in the ambient liquid. W e would like to replace this complex m anybody problem by an elective Langevin equation for the dissipative motion of the charge carriers in the nanotube, without invoking the FD T which, strictly speaking, holds only in the absence of the low. O ur treatment nonetheless captures the qualitative physics of the dissipative entrainment of carriers by the moving ions. For this, we simply take F (z;t) to be a G aussian random force eld, with zero mean and a two-point correlation C (z;t). Then from Eqn.(5), the drift velocity of the carrier u_D hdz(t)=dti = (1=)hF (z(t);t)i can be rewritten, using N ovikov's theorem [8] in relation to the G aussian noise F (z;t), as

$$u_{D} = \frac{1}{2} \int_{z,z^{0};t^{0}}^{Z} C(z z^{0};t t^{0})h \frac{(z z(t))}{F(z^{0};t^{0})}i$$

= $\frac{1}{2} \int_{z,z^{0};t^{0}}^{Z} C(z z^{0};t t^{0})h \frac{z(t)}{F(z^{0};t^{0})} (z z(t))i;$ (6)

U sing Eqn.(5) to evaluate the functional derivative in Eqn.(6), and writing C (z;t) in term s

of its Fourier transform Cq (t) yields

$$u_{\rm D} = \frac{1}{2}^{Z} - \frac{dq}{(2)^{3}} \int_{0}^{Z_{\rm I}} dth e^{iq_{\rm Z} [Z(t) - Z(t^0)]} iiq_{\rm Z} C_{\rm q}(t)$$
(7)

where is an ultraviolet cut-o of the order of an inverse ionic diameter. As in the preceding heuristic treatment, let us take the correlation $C_q(t)$ of the ions to be the Galilean boost, with velocity u_L , of an equilibrium correlation function $C_q^0(t)$, with a relaxation time q:

$$C_{q}(t) = C_{q}^{0}(t)e^{iq_{z}u_{L}t} C_{q}^{0}e^{iq_{z}u_{L}t}e^{t=q};$$
 (8)

where C_q^0 is the equilibrium equal-time correlation function of the force uctuations. This form, despite its underiable limitations, is the simplest way to capture the basic physics of ions moving past the nanotube, and admits an essentially analytical treatment. As before, the force-force correlation C_q^0 can be expressed in terms of the ionic charge-density correlation, which is known as an input from the liquid state (dilute ionic solution) theory, namely that $C_q^0 / (q_z^2 = q^4) S_q^0$ with the ionic charge structure factor $S_q^0 = q^2 = (q^2 + 2^2)$. Note the factor $(q_z^2 = q^4)$ arising from the gradient (0 = 0 z) and the Laplacian (r^2) in q-space. Replacing z (t) in Eqn.(7) by its mean u_D t for simplicity, we obtain the compact expression

$$u_{\rm D} = v \qquad \frac{\mathrm{d}q}{(2)^3} \quad \frac{1}{q_{\rm Z}^2 v^2 + q^2} \qquad \frac{\mathrm{d}q_{\rm Z}^2}{\mathrm{d}q^2 + q^2} \quad ; \qquad (9)$$

for the drift velocity of the charge carriers in the nanotube, where as before $v = u_L = u_D$, is a lum ped constant of proportionality that depends on the parameters of the liquid-state correlation function input used above. W ith the ultraviolet cut-o () set to in nity, and [7] with $1 = q = D q^2$, Eqn. (9) has precisely the form of Eqn.(1) taken in conjunction with the Eqn.(4), allowing us thereby to identify the integral on its right-hand side essentially with D = L. This gives us an expression for the ow-speed dependence of L, and thus nally an analytic expression for the charge drift velocity (u_D) as a function of the liquid ow velocity (u_L). This real m s our heuristic argument given at the beginning.

We close by sum marizing the main points of our work. First, on the experimental side, we have clearly shown that the liquid ow produces not only a voltage (i.e., not merely a capacitive charging), but a short-circuit current as well in the nanotube; that both have a sublinear dependence on the imposed ow-speed; and that the voltage/current ratio corresponds to the nanotube sample resistance. These observations are incompatible with an electrokinetic origin for the (electronic) current in the nanotube. On the theoretical side,

we have proposed a theory wherein the current is essentially a statistical consequence of the ow-induced asymmetry in the correlation of the ions, in the ambient uid as seen by the charge carriers in the nanotube. In portantly, our theory predicts in general a sublinear behavior for the electrical response, with a linear regime at only the smallest values of imposed ow. The extended logarithm ic regime seen in experiments can presumably be rationalized in detail with particular forms for the correlation function (C $_{\rm q}^{\rm 0})$ and the relaxation time (q), as inputs to be taken from the liquid state (dilute ionic solution) theory. M oreover, a realistic treatm ent will require taking into account details of the com plex, hydrophobic, inter-nanotube m icro-uidic environm ent of our m at sam ples. Thus, very speci cally, the no-slip boundary condition would in ply a decreasing velocity of the ow nearer the nanotube (the shear ow). This decrease in the ow velocity will how every be o set by the corresponding increase in its e ectiveness (via the screened coulom bic forcing) closer to the interface. The resulting levelling is expected to broaden the sublinear response and thus in prove agreem ent with the experiment. Our main point, however, is that the experiments show sublinear behavior, which is inconsistent within existing theories of ow-induced voltages and currents in nanotubes, and that our approach naturally and inevitably leads to strong sublinearity. F inally, we emphasize that the ow-induced asymmetry of the random uctuations is key to the charge-carrier drift (drag) mechanism in our theory. In this broad sense our approach here subsum es the asym metric uctuating ratchets invoked earlier [1] in a general way. In this connection, reference must be made to the idea of a drag (shear) induced by the relative motion between material surfaces, where the Doppler shifted and aberrated photonic uctuations, e.g. zero-point photons, have been invoked very e ectively [9, 10]. We would also like here to add that more than one mechanisms could very well be at work in these system s. For example, in a recent publication Persson et al [11] have invoked a combination of frictional stick-slip and barrier-hopping to explain the observed phenom enon of ow-induced voltages in SW NT. The one we propose here seem s particularly robust and general, and we look forward to experimental tests, especially of the predicted saturation of the electrical response at high ow speeds.

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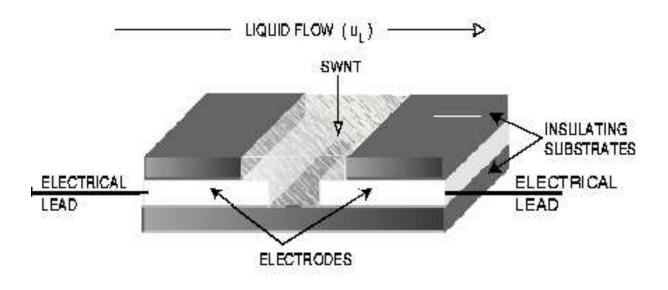


FIG.1: Schematic sketch of the nanotube ow sensor placed along the ow direction (u_L) . SW NT bundles are packed between two metal electrodes. The insulating substrate keeps the SW NT in place. The electrical leads are taken out from the metal electrodes.

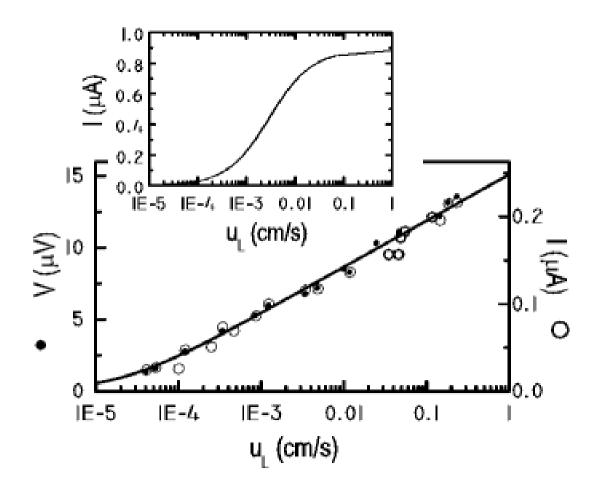


FIG.2: Voltage (full circles) and current (open circles) as functions of ow speed u_L . The solid line is a t to the logarithm ic function as explained in the text. Inset shows the theoretical plot of current (I = neu_D A) versus ow speed based on Eqn.(1,4) for typical choice of parameters: T = 300K; = 80 (CGS units); D = 10⁴ cm/s; _D = 10¹⁶ s; ₀ = 10¹³ cm³; charge carrier density in nanotubes (n = 10¹⁸ cm³); cross-sectional-area (A) = 10³ cm². The strong sublinearity is clearly seen.

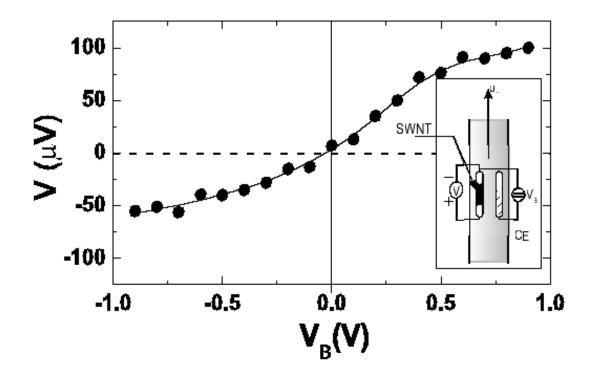


FIG.3: Flow-induced voltage as a function of bias V_B . Inset: schematic of electrochemical biasing of the nanotubes; CE is the counterelectrode. The solid line is a guide to the eye